Electronic Supplementary Material (ESI) for Materials Advances.

Supporting Information:

Out of stoichiometry $CuCrO_2$ films as promising p-type TCO for transparent electronics

Lorenzo Bottiglieri* [a], João Resende [b], Matthieu Weber [a], Odette Chaix-Pluchery[a], Carmen Jiménez [a], Jean-Luc Deschanvres [a]

a. Univ. Grenoble Alpes, CNRS, Grenoble INP, LMGP, 38000 Grenoble, France

b. AlmaScience, Campus da Caparica, 2829-516 Caparica, Portugal

Email: Lorenzo.bottiglieri@grenoble-inp.fr

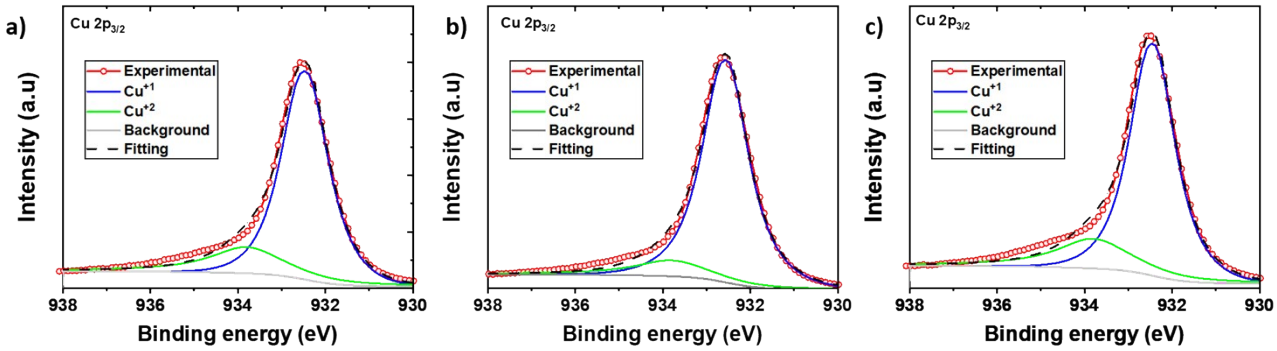

Figure S1. Cu $2p_{3/2}$ experimental peak and its fitting for a) Cu-rich $CuCrO_2$:59%, b) Cu-rich $CuCrO_2$:65% and c) Cu_2O+$CuCrO_2$:73%.

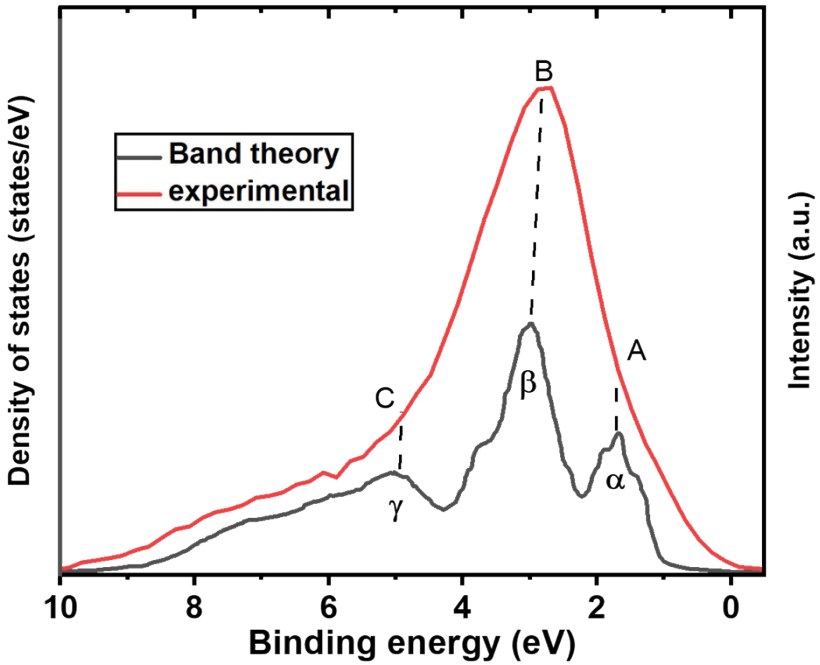

Figure S2. Comparison between the theoretical density of states of $CuCrO_2$, adapted by Yokobori et al[1]*. and the valence band spectra of Cu-rich $CuCrO_2$ with Cu/(Cu+Cr)=65%. The energy zero was set to the Fermi level.*

1. Yokobori, T. *et al.* Electronic structure of the hole-doped delafossite oxides $CuCr_{1-x}Mg_xO_2$. *Phys. Rev. B - Condens. Matter Mater. Phys.* **87**, (2013).